

GaAs-IR-Lumineszenzdiode

GaAs Infrared Emitter

LD 261



Wesentliche Merkmale

- GaAs-IR-Lumineszenzdiode
- Hohe Zuverlässigkeit
- Gruppiert lieferbar
- Gehäusegleich mit BPX 81
- Miniatur-Gehäuse

Anwendungen

- Miniaturlichtschranken für Gleich- und Wechsellichtbetrieb
- Barcodeleser
- Industrieelektronik
- „Messen/Steuern/Regeln“
- Sensorik
- Drehzahlsteuerung

Features

- GaAs infrared emitting diode
- High reliability
- Available in bins
- Same package as BPX 81
- Miniature package

Applications

- Miniature photointerrupters
- Barcode readers
- Industrial electronics
- For control and drive circuits
- Sensor technology
- Speed controller

| Typ Type | Bestellnummer Ordering Code | Gehäuse Package |
|-------------|--------------------------------|--|
| LD 261 | Q62703-Q395 | Leiterbandgehäuse, klares Epoxy-Gießharz, linsenförmig im 2.54-mm-Raster ($\frac{1}{10}$ "), Kathodenkennzeichnung: Nase am Lötspieß |
| LD 261-5 | Q62703-Q67 | Lead frame, transparent epoxy resin lens, solder tabs lead spacing 2.54 mm ($\frac{1}{10}$ "), cathode marking: projection at solder lead |

Grenzwerte ($T_A = 25 \text{ }^\circ\text{C}$)**Maximum Ratings**

| Bezeichnung Parameter | Symbol Symbol | Wert Value | Einheit Unit |
|--|--------------------------|-----------------------|-------------------------|
| Betriebs- und Lagertemperatur Operating and storage temperature range | $T_{op}; T_{stg}$ | -40 ... +80 | $^\circ\text{C}$ |
| Sperrsichttemperatur Junction temperature | T_j | 80 | $^\circ\text{C}$ |
| Sperrspannung Reverse voltage | V_R | 5 | V |
| Durchlaßstrom Forward current | I_F | 50 | mA |
| Stoßstrom, $\tau \leq 10 \mu\text{s}, D = 0$ Surge current | I_{FSM} | 1.6 | A |
| Verlustleistung Power dissipation | P_{tot} | 70 | mW |
| Wärmewiderstand Thermal resistance | R_{thJA} R_{thJL} | 750 650 | K/W K/W |

Kennwerte ($T_A = 25 \text{ }^\circ\text{C}$)**Characteristics**

| Bezeichnung Parameter | Symbol Symbol | Wert Value | Einheit Unit |
|--|------------------------------|-----------------------|-------------------------|
| Wellenlänge der Strahlung Wavelength at peak emission $I_F = 50 \text{ mA}, t_p = 20 \text{ ms}$ | λ_{peak} | 950 | nm |
| Spektrale Bandbreite bei 50% von I_{max} Spectral bandwidth at 50% of I_{max} $I_F = 50 \text{ mA}, t_p = 20 \text{ ms}$ | $\Delta\lambda$ | 55 | nm |
| Abstrahlwinkel Half angle | ϕ | ± 15 | Grad deg. |
| Aktive Chipfläche Active chip area | A | 0.25 | mm^2 |
| Abmessungen der aktiven Chipfläche Dimension of the active chip area | $L \times B$ $L \times W$ | 0.5×0.5 | mm |
| Abstand Chipoberfläche bis Linsenscheitel Distance chip surface to lens top | H | 1.3 ... 1.9 | mm |

Kennwerte ($T_A = 25^\circ\text{C}$)

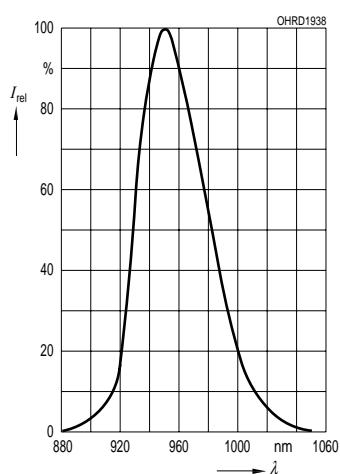
Characteristics (cont'd)

| Bezeichnung Parameter | Symbol Symbol | Wert Value | Einheit Unit |
|---|------------------|---------------------|-----------------|
| Schaltzeiten, I_e von 10% auf 90% und von 90% auf 10%, bei $I_F = 50 \text{ mA}$, $R_L = 50 \Omega$ Switching times, I_e from 10% to 90% and from 90% to 10%, $I_F = 50 \text{ mA}$, $R_L = 50 \Omega$ | t_r, t_f | 1 | μs |
| Kapazität, $V_R = 0 \text{ V}$ Capacitance | C_o | 40 | pF |
| Durchlaßspannung Forward voltage $I_F = 50 \text{ mA}$, $t_p = 20 \mu\text{s}$ | V_F | 1.25 (≤ 1.4) | V |
| Sperrstrom, $V_R = 5 \text{ V}$ Reverse current | I_R | 0.01 (≤ 1) | μA |
| Gesamtstrahlungsfluß Total radiant flux $I_F = 50 \text{ mA}$, $t_p = 20 \text{ ms}$ | Φ_e | 9 | mW |
| Temperaturkoeffizient von I_e bzw. Φ_e , $I_F = 50 \text{ mA}$ Temperature coefficient of I_e or Φ_e , $I_F = 50 \text{ mA}$ | TC_I | - 0.55 | %/K |
| Temperaturkoeffizient von V_F , $I_F = 50 \text{ mA}$ Temperature coefficient of V_F , $I_F = 50 \text{ mA}$ | TC_V | - 1.5 | mV/K |
| Temperaturkoeffizient von λ_{peak} , $I_F = 50 \text{ mA}$ Temperature coefficient of λ_{peak} , $I_F = 50 \text{ mA}$ | TC_λ | 0.3 | nm/K |

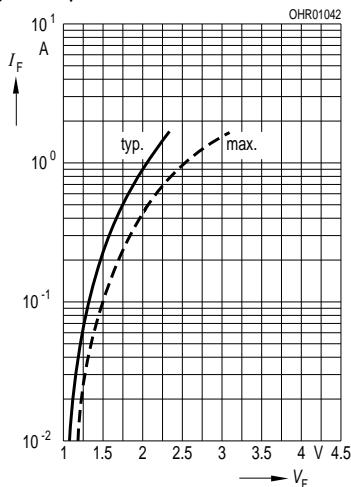
Gruppierung der Strahlstärke I_e in Achsrichtunggemessen bei einem Raumwinkel $\Omega = 0.01 \text{ sr}$ **Grouping of radiant intensity I_e in axial direction**at a solid angle of $\Omega = 0.01 \text{ sr}$

| Bezeichnung Parameter | Symbol | Werte Values | | Einheit Unit |
|--|--------|-----------------|-------------|-----------------|
| | | LD 261 | LD 261-5 | |
| Strahlstärke Radiant intensity $I_F = 50 \text{ mA}$, $t_p = 20 \text{ ms}$ | I_e | 2 ... 10 | 3.2 ... 6.3 | mW/sr |

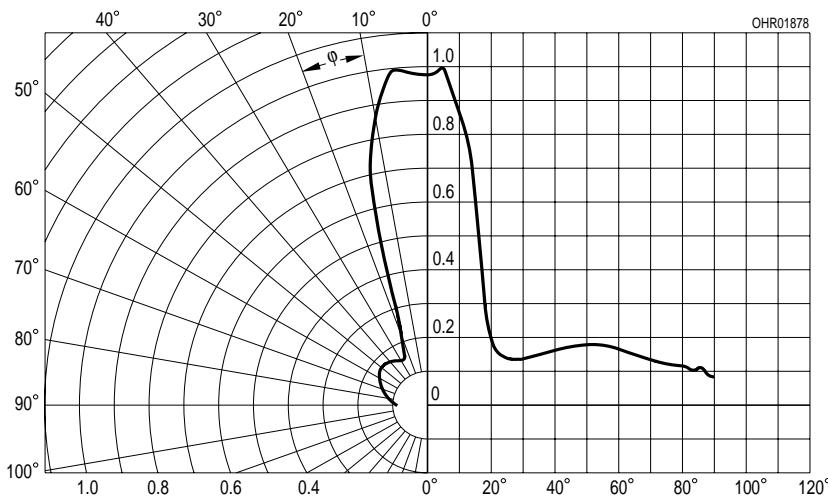
Relative Spectral Emission
 $I_{\text{rel}} = f(\lambda)$



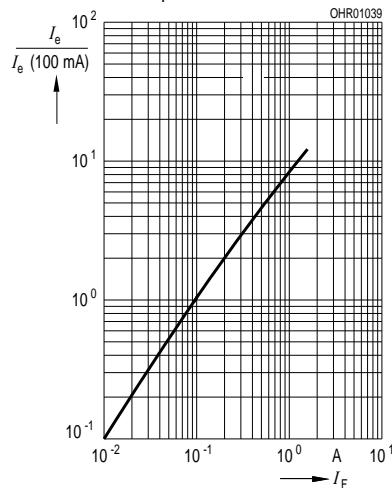
Forward Current
 $I_F = f(V_F)$, single pulse,
 $t_p = 20 \mu\text{s}$



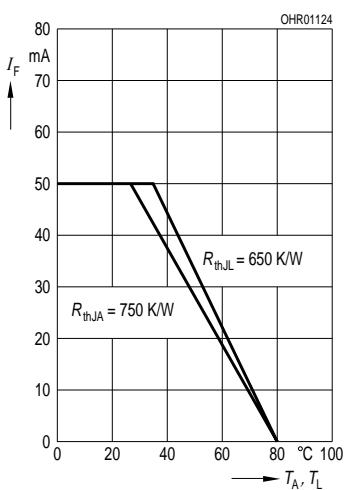
Radiation Characteristics $I_{\text{rel}} = f(\phi)$



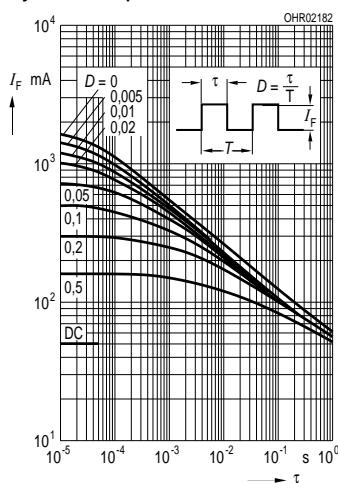
Radiant Intensity $\frac{I_e}{I_e \text{ 100 mA}} = f(I_F)$
Single pulse, $t_p = 20 \mu\text{s}$



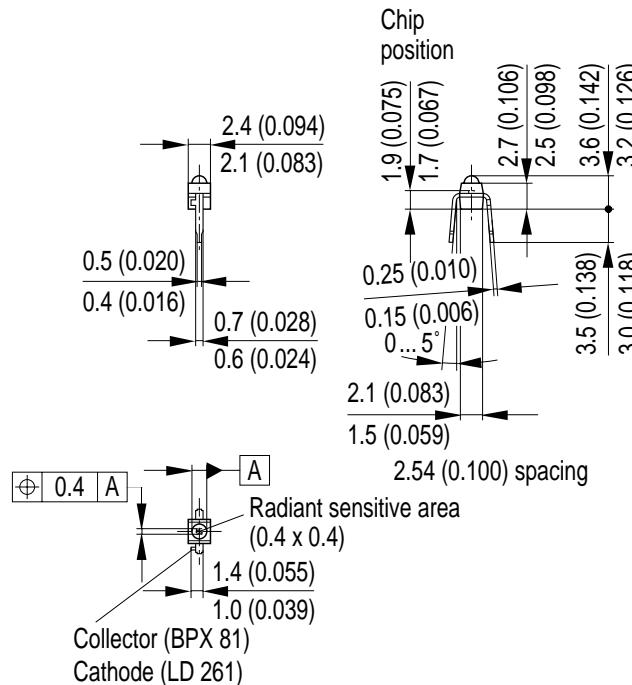
Max. Permissible Forward Current
 $I_F = f(T_A)$



Permissible Pulse Handling Capability $I_F = f(\tau)$, $T_C = 25^\circ\text{C}$,
duty cycle $D = \text{parameter}$



Maßzeichnung
Package Outlines



1) Detaching area for tools, flash not true to size.

Approx. weight 0.03 g

GEOY6021

Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

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